

International
IR Rectifier
 SCHOTTKY RECTIFIER
 HIGH EFFICIENCY SERIES

PD - 94288A

30LJQ045

30 Amp, 45V

Major Ratings and Characteristics

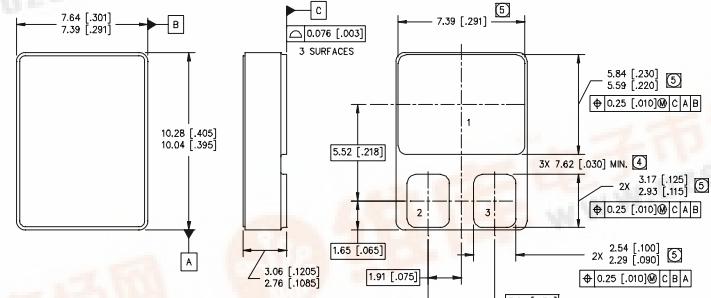
Characteristics	30LJQ045	Units
I _{F(AV)}	30	A
V _{RRM}	45	V
I _{FSM} @ t _p = 8.3ms half-sine	100	A
V _F @ 30Apk, T _J = 125°C	0.66	V
T _J , T _{stg} Operating and storage	-55 to 150	°C

Description/Features

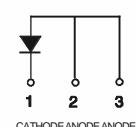
The 30LJQ045 Schottky rectifier has been expressly designed to meet the rigorous requirements of hi-rel environments. It is packaged in the hermetic surface mount SMD-0.5 ceramic package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source control drawings to TX, TXV and S quality levels.

- Hermetically Sealed
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long term Reliability
- Surface Mount
- Lightweight

CASE STYLE



NOTES:
 1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
 ④ DIMENSION INCLUDES METALLIZATION FLASH.
 ⑤ DIMENSION DOES NOT INCLUDE METALLIZATION FLASH.



IR Case Style SMD-0.5

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Voltage Ratings

Part number	30LJQ045		
V_R Max. DC Reverse Voltage (V)	45		
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	Limits	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current See Fig. 5	30	A	50% duty cycle @ $T_C = 107^\circ\text{C}$, square waveform
I_{FSM} Max. Peak One Cycle Non - Repetitive Surge Current	100	A	@ $t_p = 8.3$ ms half-sine

Electrical Specifications

Parameters	Limits	Units	Conditions
V_{FM} Max. Forward Voltage Drop See Fig. 1①	0.86	V	@ 30A
	1.07	V	@ 60A
	0.71	V	@ 30A
	0.94	V	@ 60A
	0.66	V	@ 30A
	0.88	V	@ 60A
I_{RM} Max. Reverse Leakage Current See Fig. 2①	0.1	mA	$T_J = 25^\circ\text{C}$
	3.6	mA	$T_J = 100^\circ\text{C}$
	20	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	1300	pF	$V_R = 5\text{V}_{\text{DC}}$ (1MHz, 25°C)
L_s Typical Series Inductance	4.8	nH	Measured from center of cathode pad to center of anode pad

Thermal-Mechanical Specifications

Parameters	Limits	Units	Conditions
T_J Max.Junction Temperature Range	-55 to 150	°C	
T_{stg} Max. Storage Temperature Range	-55 to 150	°C	
R_{thJC} Max. Thermal Resistance, Junction to Case	1.6	°C/W	DC operation See Fig. 4
wt Weight (Typical)	1.0	g	
Die Size (Typical)	115X170	mils	
Case Style	SMD-0.5		

① Pulse Width < 300μs, Duty Cycle < 2%
 ② Pins 2 and 3 externally tied together

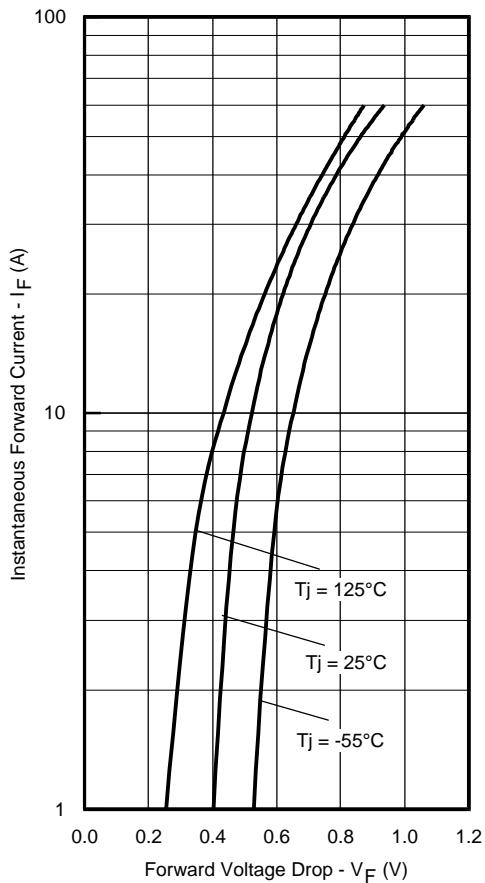


Fig. 1 - Max. Forward Voltage Drop Characteristics

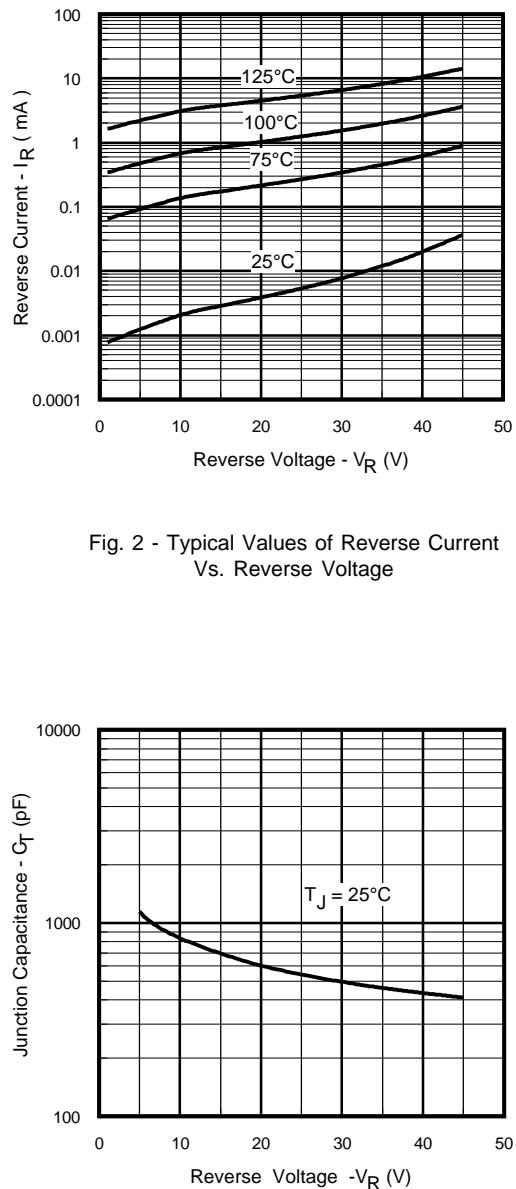


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

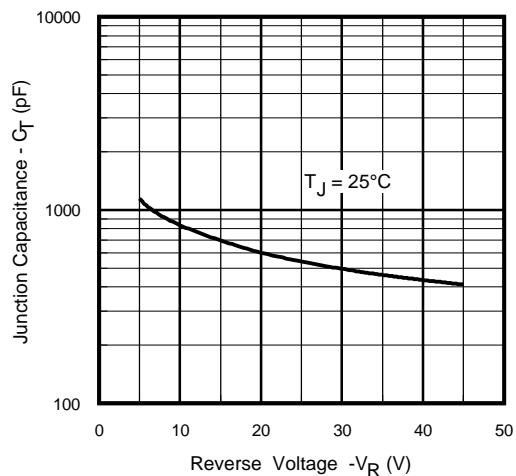


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

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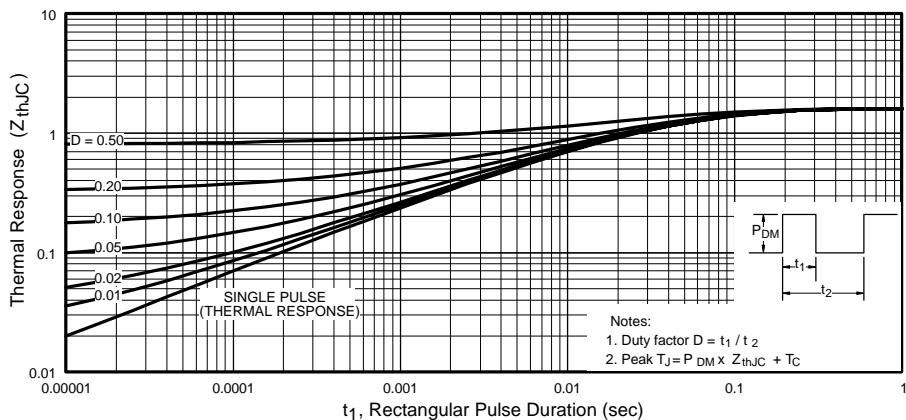


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

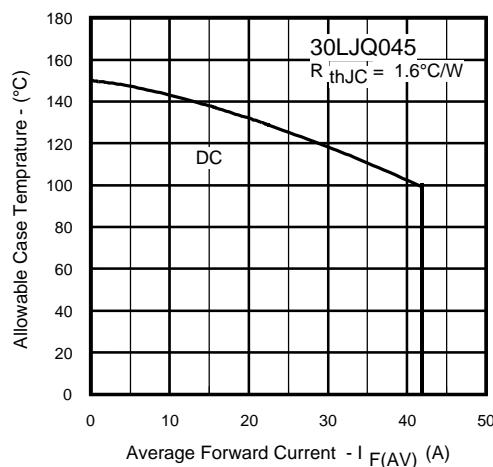


Fig. 5 - Max. Allowable Case Temperature Vs.
Average Forward Current

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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7903

Visit us at www.irf.com for sales contact information.
Data and specifications subject to change without notice. 08/01